

# PSMN1R1-80CSF

# NextPower 80 V, 1.16 mOhm, N-channel MOSFET in CCPAK1212i package

6 December 2024

Product data sheet

## 1. General description

NextPower 80 V, standard level gate drive MOSFET. Qualified to 175 °C and recommended for high power industrial and consumer applications.

#### 2. Features and benefits

- Low Q<sub>rr</sub> for higher efficiency and lower spiking
- 385 Amps I<sub>D(max)</sub> continuous current rating
- Low Q<sub>G</sub> × R<sub>DSon</sub> FOM for high efficiency switching applications
- Strong avalanche energy rating (E<sub>as</sub>)
- Avalanche rated and 100% tested
- Ha-free and RoHS compliant CCPAK1212i package
- · Inverted package, suitable for top-side cooling

## 3. Applications

- Battery protection
- · High power full and half-bridge configurations
- BLDC motor control
- OR-ing

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	М	in Typ	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C	-	-	80	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	-	-	385	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>	-	-	935	W
Static char	acteristics					
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = 10 V; $I_{D}$ = 25 A; $T_{j}$ = 25 °C; Fig. 11	-	0.92	1.16	mΩ
Dynamic cl	haracteristics			'		
$Q_{GD}$	gate-drain charge	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 40 V; V <sub>GS</sub> = 10 V; T <sub>j</sub> = 25 °C; <u>Fig. 13</u> ; <u>Fig. 14</u>	1	37	86	nC



# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		
2	S	source		
3	S	source	12 11 10 9 8 7	
4	S	source		
5	S	source		
6	G	gate	] U	D
7	D	drain		
8	D	drain		G T
9	D	drain		mbb076 S
10	D	drain	1 2 3 4 5 6	
11	D	drain	sot8005a_sv	
12	D	drain	CCPAK1212i (SOT8005A)	
mb	D	mounting base; connected to drain		

# 6. Ordering information

**Table 3. Ordering information** 

Type number Package			
	Name	Description	Version
PSMN1R1-80CSF	CCPAK1212i	Plastic, surface mounted copper clip package (CCPAK1212i); 12 terminals; 2.0 mm pitch, 12 mm × 12 mm × 2.5 mm body	SOT8005A

# 7. Marking

## Table 4. Marking codes

Type number	Marking code
PSMN1R1-80CSF	XP1F1S80C

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).  $T_i$  = 25 °C unless otherwise stated.

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C	-	80	V
$V_{DGR}$	drain-gate voltage	25 °C ≤ $T_j$ ≤ 175 °C; $R_{GS}$ = 20 kΩ	-	80	V
V <sub>GS</sub>	gate-source voltage		-20	20	V
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>	-	935	W
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	-	385	А
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 2</u>	-	385	Α
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 \text{ °C}$ ; Fig. 3	-	2367	Α

Symbol	Parameter	Conditions		Min	Max	Unit
T <sub>stg</sub>	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T <sub>sld(M)</sub>	peak soldering temperature			-	260	°C
Source-drain	n diode			'	'	'
Is	source current	T <sub>mb</sub> = 25 °C		-	315	Α
I <sub>SM</sub>	peak source current	pulsed; t <sub>p</sub> ≤ 10 μs; T <sub>mb</sub> = 25 °C		-	2367	Α
Avalanche r	uggedness				'	
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$I_D$ = 109 A; $V_{sup} \le 80$ V; $R_{GS}$ = 50 Ω; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; unclamped; $t_p$ = 230 μs; Fig. 4	[1]	-	1300	mJ
I <sub>AS</sub>	non-repetitive avalanche current	$V_{sup}$ = 80 V; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; $R_{GS}$ = 50 $\Omega$ ; Fig. 4	[1]	-	109	А

#### [1] Protected by 100% test

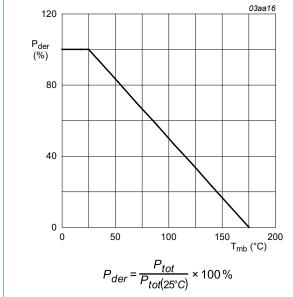
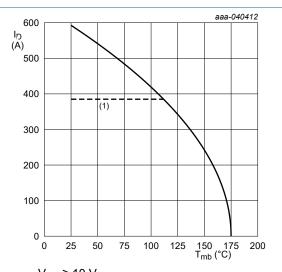
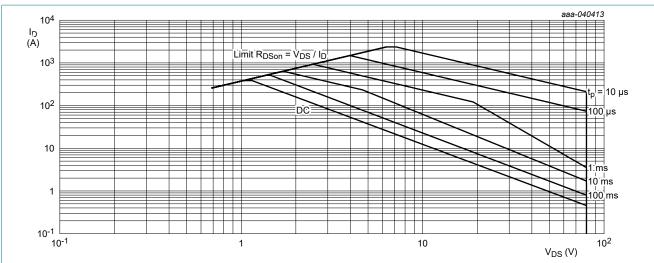


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



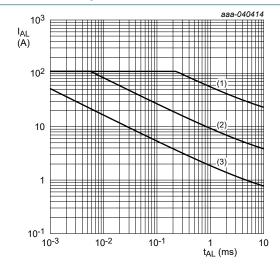
 $V_{GS} \ge 10 \text{ V}$  (1) 385 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

Fig. 2. Continuous drain current as a function of mounting base temperature



T<sub>mb</sub> = 25 °C; I<sub>DM</sub> is a single pulse

Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage



(1)  $T_{j \text{ (init)}}$  = 25 °C; (2)  $T_{j \text{ (init)}}$  = 150 °C; (3) Repetitive Avalanche

Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 5	-	0.123	0.16	K/W
R <sub>th(j-a)</sub>	thermal resistance from	Fig. 6	-	58	-	K/W
	junction to ambient	Fig. 7	-	29	-	K/W

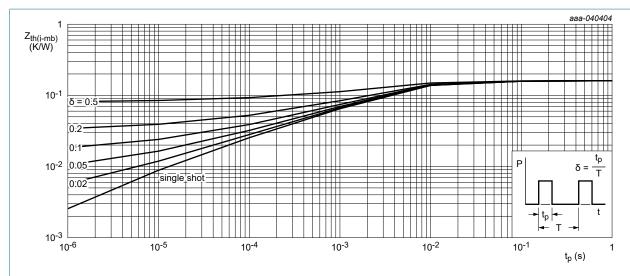


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

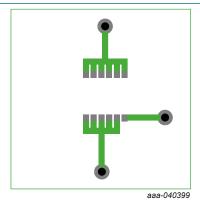
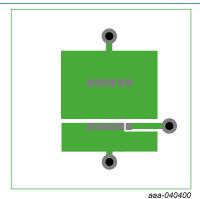


Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient

70 µm thick copper on FR4 board



Copper area 25.4 mm square; 70  $\mu m$  thick on FR4 board

Fig. 7. PCB layout for thermal resistance from junction to ambient

## 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	cteristics					
V <sub>(BR)DSS</sub>	drain-source	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	80	-	-	V
	breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -55 °C	72	-	-	V
V <sub>GS(th)</sub>	gate-source threshold	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	2	3	4	V
	voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C}$	-	1.52	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}$	-	3.5	-	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T <sub>j</sub> ≤ 150 °C	-	-8.91	-	mV/K
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 80 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.15	1.6	μΑ
		V <sub>DS</sub> = 80 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 125 °C	-	42	160	μΑ
I <sub>GSS</sub>	gate leakage current	$V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	2	100	nA
		V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = 10 V; $I_{D}$ = 25 A; $T_{j}$ = 25 °C; Fig. 11	-	0.92	1.16	mΩ
		$V_{GS}$ = 10 V; $I_D$ = 25 A; $T_j$ = 100 °C; Fig. 12	-	1.5	1.8	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 175 °C; Fig. 12	-	2.1	2.7	mΩ
		$V_{GS} = 7 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ °C}; Fig. 11$	-	1.18	1.77	mΩ
$R_G$	gate resistance	f = 1 MHz; T <sub>j</sub> = 25 °C	0.56	1.12	2.24	Ω
Dynamic ch	aracteristics					
Q <sub>G(tot)</sub>	total gate charge	$I_D$ = 25 A; $V_{DS}$ = 40 V; $V_{GS}$ = 10 V; $T_j$ = 25 °C; <u>Fig. 13</u> ; <u>Fig. 14</u>	121	242	363	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 ^{\circ}\text{C}$	-	221	-	nC
Q <sub>GS</sub>	gate-source charge	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 40 V; V <sub>GS</sub> = 10 V;	43	72	101	nC
Q <sub>GS(th)</sub>	pre-threshold gate- source charge	T <sub>j</sub> = 25 °C; <u>Fig. 13; Fig. 14</u>	-	47	-	nC
Q <sub>GS(th-pl)</sub>	post-threshold gate- source charge		-	23	-	nC
$Q_{GD}$	gate-drain charge		11	37	86	nC
V <sub>GS(pl)</sub>	gate-source plateau voltage	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 40 V; T <sub>j</sub> = 25 °C; Fig. 13; Fig. 14	-	4.3	-	V
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 40 V; V <sub>GS</sub> = 0 V; f = 1 MHz;	10554	17591	24627	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C; <u>Fig. 15</u>	2557	4261	6818	pF
C <sub>rss</sub>	reverse transfer capacitance		8	83	250	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS} = 40 \text{ V}; R_L = 1.6 \Omega; V_{GS} = 10 \text{ V};$	-	66	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega$ ; $T_j = 25 °C$	-	51	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	155	-	ns
t <sub>f</sub>	fall time		-	69	-	ns
Source-drai	n diode		1	1	1	
V <sub>SD</sub>	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}; Fig. 16$	-	0.75	1	V
t <sub>rr</sub>	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$	-	61	-	ns
		$_{DS} = 40 \text{ V; } T_j = 25 \text{ °C; } \frac{\text{Fig. } 17}{\text{ Fig. } 17}$				

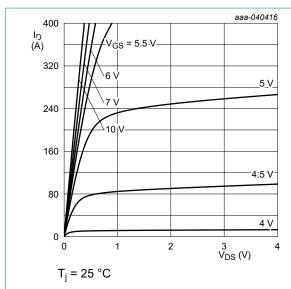


Fig. 8. Output characteristics; drain current as a function of drain-source voltage; typical values

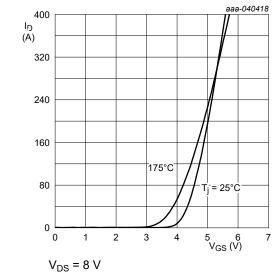


Fig. 10. Transfer characteristics; drain current as a function of gate-source voltage; typical values

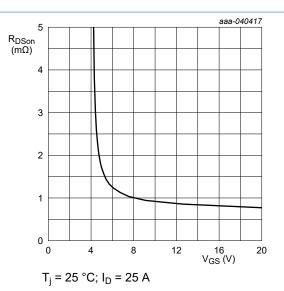


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

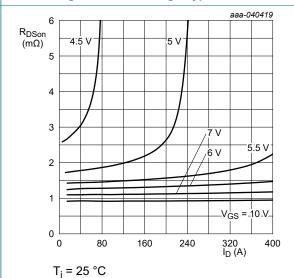


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

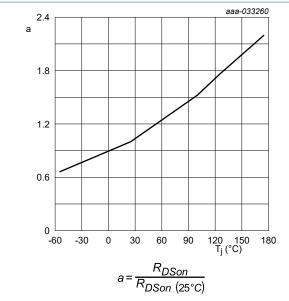


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

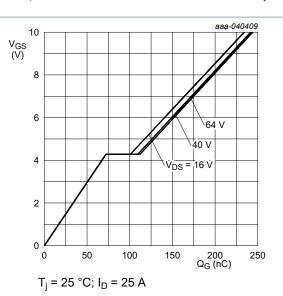


Fig. 13. Gate-source voltage as a function of gate charge; typical values

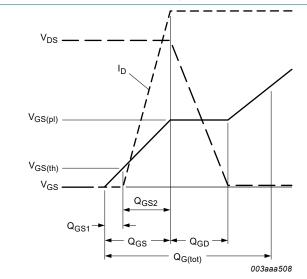
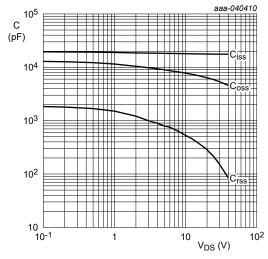


Fig. 14. Gate charge waveform definitions



 $V_{GS} = 0 V$ ; f = 1 MHz

Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

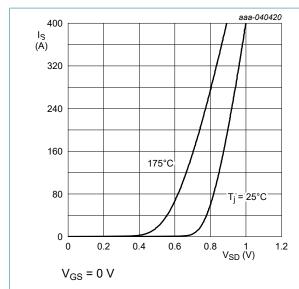


Fig. 16. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

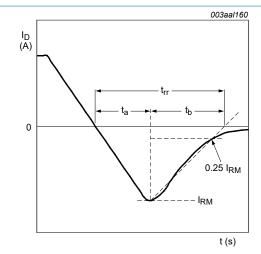
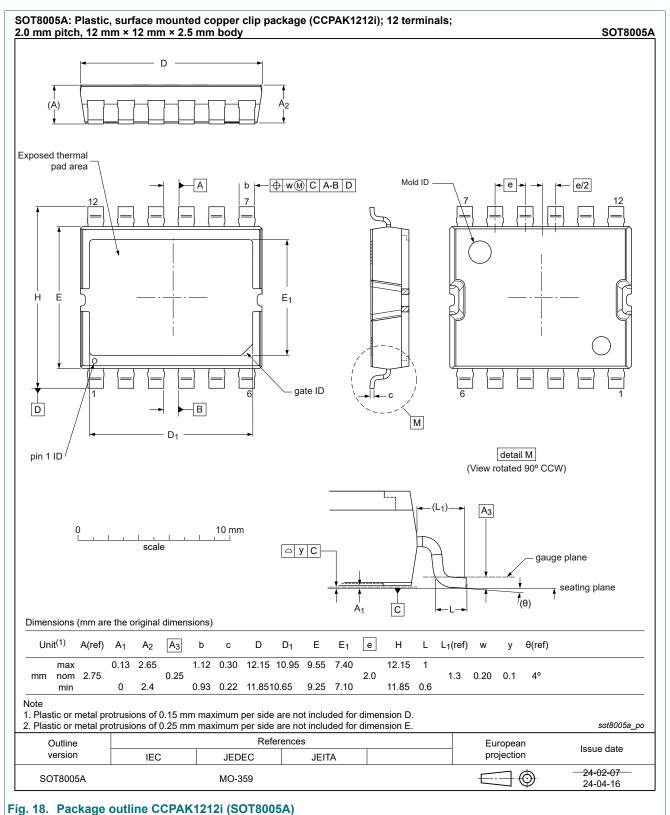
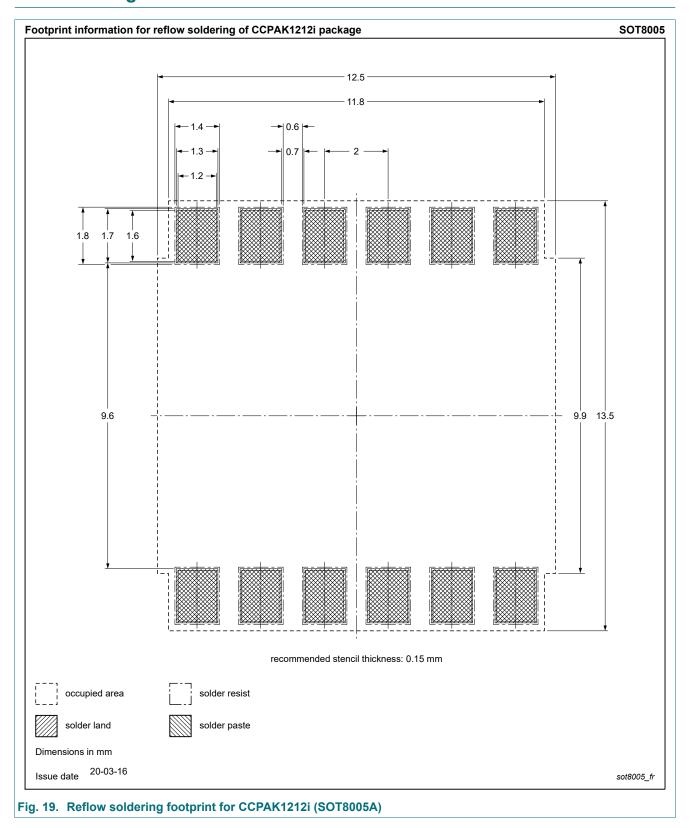


Fig. 17. Reverse recovery timing definition

# 11. Package outline



# 12. Soldering



## 13. Legal information

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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